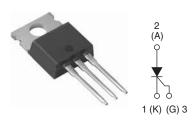


Vishay High Power Products

Phase Control SCR, 10 A



TO-220AB

PRODUCT SUMMARY			
V _T at 6.5 A	< 1.15 V		
I _{TSM}	140 A		
V _{RRM}	800 V		

DESCRIPTION/FEATURES

The 10TTS08PbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control RoHS* applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.



Typical applications are in input rectification and crow-bar (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

Also available in SMD-220 package (series 10TTS08SPbF).

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter T _A = 55 °C, T _J = 125 °C, common heatsink of 1 °C/W	13.5	17	А	

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	6.5		
I _{T(RMS)}		10	Α	
V _{RRM} /V _{DRM}		800	V	
I _{TSM}		140	А	
V _T	6.5 A, T _J = 25 °C	1.15	V	
dV/dt		150	V/µs	
dl/dt		100	A/µs	
T _J	Range	- 40 to 125	°C	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
10TTS08PbF	800	800	1.0		

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduction half sine wave		6.5	
Maximum RMS on-state current	I _{T(RMS)}	1 _C = 112 °C, 180 °Cond	uction hall sine wave	10	۸
Maximum peak, one-cycle,		10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	120	A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volt	age reapplied, T _J = 125 °C	140	
Maximum 124 for fusing	12+	10 ms sine pulse, rated	V _{RRM} applied, T _J = 125 °C	72	A ² s
Maximum I ² t for fusing	l ² t	10 ms sine pulse, no volt	age reapplied, T _J = 125 °C	100	A-S
Maximum I ² √t for fusing	I²√t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = 125$ °C		1000	A²√s
Maximum on-state voltage drop	V_{TM}	6.5 A, T _J = 25 °C		1.15	V
On-state slope resistance	r _t	− T _J = 125 °C		17.3	mΩ
Threshold voltage	V _{T(TO)}			0.85	V
Maximum various and divest leakage accurant	1 /1	T _J = 25 °C	V _R = Rated V _{RRM} /V _{DRM}	0.05	
Maximum reverse and direct leakage current	I_{RM}/I_{DM}	T _J = 125 °C		1.0	
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I _T = 1 A		30	mA
Maximum latching current	IL	Anode supply = 6 V, resistive load		50	
Maximum rate of rise of off-state voltage	dV/dt	T _J = 25 °C		150	V/µs
Maximum rate of rise of turned-on current	dl/dt			100	A/µs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P_{GM}		8.0	w	
Maximum average gate power	P _{G(AV)}		2.0	VV	
Maximum peak positive gate current	+I _{GM}		1.5	Α	
Maximum peak negative gate voltage	-V _{GM}		10	V	
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA V	
		Anode supply = 6 V, resistive load, T _J = 25 °C	15		
		Anode supply = 6 V, resistive load, T _J = 125 °C	10		
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2		
		Anode supply = 6 V, resistive load, T _J = 25 °C	1		
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7		
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value 0.2 0.1			
Maximum DC gate current not to trigger	I _{GD}			mA	

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8	
Typical reverse recovery time	t _{rr}	T ₁ = 125 °C	3	μs
Typical turn-off time	tq	100 100		



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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J , T_{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	oz.
Marratina taunus	minimum			6 (5)	kgf · cm
Mounting torque -	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220AB	10TTS08	

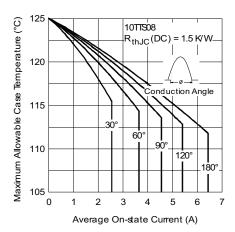


Fig. 1 - Current Rating Characteristics

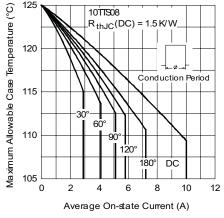


Fig. 2 - Current Rating Characteristic

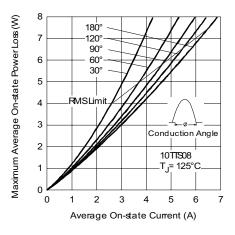


Fig. 3 - On-State Power Loss Characteristics

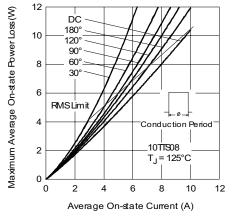


Fig. 4 - On-State Power Loss Characteristics

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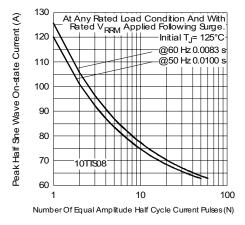


Fig. 5 - Maximum Non-Repetitive Surge Current

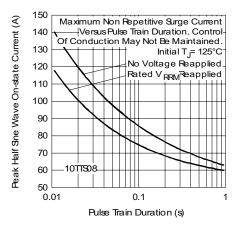


Fig. 6 - Maximum Non-Repetitive Surge Current

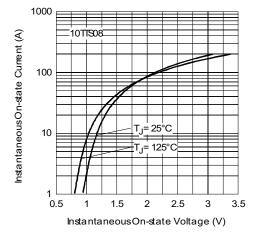


Fig. 7 - On-State Voltage Drop Characteristics

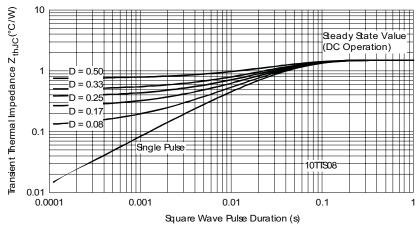


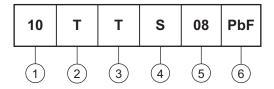
Fig. 8 - Thermal Impedance ZthJC Characteristics



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ORDERING INFORMATION TABLE

Device code



1 - Current rating

2 - Circuit configuration:

T = Single thyristor

- Package:

T = TO-220AB

4 - Type of silicon:

S = Converter grade

Voltage code x 100 = V_{RRM}

6 - • None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95222			
Part marking information	http://www.vishay.com/doc?95225		

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